A110a0

Unitized Semiconductor Devices - Page 1 of 1



base open all

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Inclosure Material:	
Metal	
Overall Length:	
0.085 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.270 inches	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
То-70	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
55.0 breakdown voltage, collector-to-base, emitter open all transistor and 55.0 breakdown voltage	e, collector-to-emitter, l
transistor and 7.0 emitter to base voltage, static, collector open all transistor	
Current Rating Per Characteristic:	
10.00 milliamperes source cutoff current all transistor	
Power Rating Per Characteristic:	
400.0 milliwatts small-signal input power, common-collector preset all transistor	
Transfer Ratio:	
175.0 small-signal short-circuit forward current transfer ratio, common-emitter all transistor	
Special Features:	
All transistor junction pattern arrangement: pnp	
Terminal Type And Quantity:	
8 uninsulated wire lead	
Specification Data:	
80131-release5288 professional/industrial association specification	
Shelf Life:	
N/a	
Unit Of Measure:	
-	
Demilitarization:	
No	
Filg:	